

Vishay Semiconductors

# **Transmissive Optical Sensor with Phototransistor Output**

#### **Description**

This device has a compact construction where the emitting-light sources and the detectors are located face-to-face on the same optical axis. The operating wavelength is 950 nm. The detector consists of a phototransistor.

#### **Applications**

Contactless optoelectronic switch, control and counter

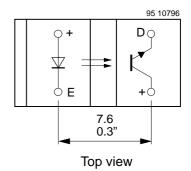




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#### **Features**

- Compact construction
- No setting efforts
- Polycarbonate case protected against ambient light
- 2 case variations
- 3 different apertures
- CTR selected in groups (regarding fourth number of type designation)



#### **Order Instruction**

Ordering Code	Resolution (mm) / Aperture (mm)	Remarks
TCST1103 <sup>A)</sup>	0.6 / 1.0	No mounting flags
TCST2103 <sup>B)</sup>		With two mounting flags
TCST1202 <sup>A)</sup>	0.4 / 0.5	No mounting flags
TCST2202 <sup>B)</sup>		With two mounting flags
TCST1300 <sup>A)</sup>	0.2 / 0.25	No mounting flags
TCST2300 <sup>B)</sup>		With two mounting flags

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# **Absolute Maximum Ratings**

## Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		$V_{R}$	6	V
Forward current		l <sub>F</sub>	60	mA
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	3	Α
Power dissipation	$T_{amb} \le 25$ °C	$P_{V}$	100	mW
Junction temperature		T <sub>i</sub>	100	°C

#### Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		I <sub>C</sub>	100	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	200	mA
Power dissipation	T <sub>amb</sub> ≤ 25 °C	$P_V$	150	mW
Junction temperature		T <sub>i</sub>	100	°C

#### Coupler

Parameter	Test Conditions	Symbol	Value	Unit
Total power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>tot</sub>	250	mW
Operating temperature range		T <sub>amb</sub>	-55 to +85	°C
Storage temperature range		T <sub>sta</sub>	-55 to +100	°C
Soldering temperature	2 mm from case, t ≤ 5 s	T <sub>sd</sub>	260	°C



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## **Electrical Characteristics** $(T_{amb} = 25^{\circ}C)$

#### Input (Emitter)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I <sub>F</sub> = 60 mA	$V_{F}$		1.25	1.6	٧
Junction capacitance	$V_R = 0$ , $f = 1 MHz$	C <sub>i</sub>		50		pF

## Output (Detector)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Collector emitter voltage	I <sub>C</sub> = 1 mA	V <sub>CEO</sub>	70			V
Emitter collector voltage	I <sub>E</sub> = 10 μA	V <sub>ECO</sub>	7			V
Collector dark current	$V_{CE} = 25 \text{ V}, I_F = 0, E = 0$	I <sub>CEO</sub>			100	nA

## Coupler

Parameter	Test Conditions	Туре	Symbol	Min.	Тур.	Max.	Unit
Current transfer ratio	$V_{CE} = 5 \text{ V},$ $I_F = 20 \text{ mA}$	TCST1103, TCST2103	CTR	10	20		%
		TCST1202, TCST2202	CTR	5	10		%
		TCST1300, TCST2300	CTR	1.25	2.5		%
Collector current	$V_{CE} = 5 \text{ V},$ $I_F = 20 \text{ mA}$	TCST1103, TCST2103	I <sub>C</sub>	2	4		mA
		TCST1202, TCST2202	I <sub>C</sub>	1	2		mA
		TCST1300, TCST2300	I <sub>C</sub>	0.25	0.5		mA
Collector emitter saturation voltage	$I_F = 20 \text{ mA},$ $I_C = 1 \text{ mA}$	TCST1103, TCST2103	V <sub>CEsat</sub>			0.4	V
	$I_F = 20 \text{ mA},$ $I_C = 0.5 \text{ mA}$	TCST1202, TCST2202	V <sub>CEsat</sub>			0.4	V
	$I_F = 20 \text{ mA},$ $I_C = 0.1 \text{ mA}$	TCST1300, TCST2300	V <sub>CEsat</sub>			0.4	V
Resolution, path of the shutter crossing the radiant sensitive zone	I <sub>Crel</sub> = 10 to 90%	TCST1103, TCST2103	S		0.6		mm
		TCST1202, TCST2202	S		0.4		mm
		TCST1300, TCST2300	S		0.2		mm





## **Switching Characteristics**

Parameter	Test Conditions	Symbol	Тур.	Unit
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega \text{ (see figure 1)}$	t <sub>on</sub>	10.0	μs
Turn-off time		t <sub>off</sub>	8.0	μs

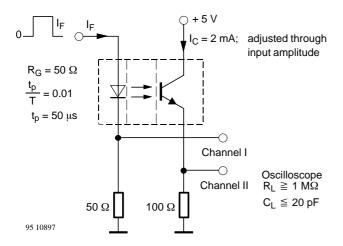


Figure 1. Test circuit, saturated operation

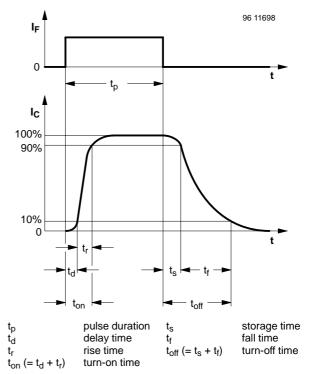


Figure 2. Switching times





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## **Typical Characteristics** (T<sub>amb</sub> = 25°C, unless otherwise specified)

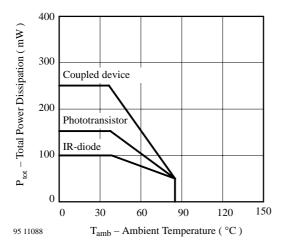


Figure 3. Total Power Dissipation vs. Ambient Temperature

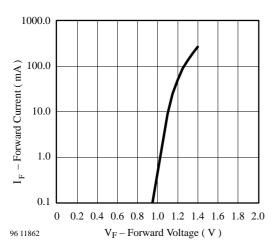


Figure 4. Forward Current vs. Forward Voltage

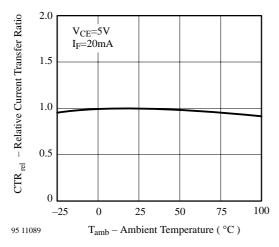


Figure 5. Relative Current Transfer Ratio vs.

Ambient Temperature

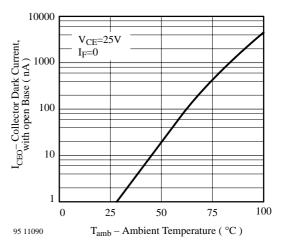


Figure 6. Collector Dark Current vs. Ambient Temperature

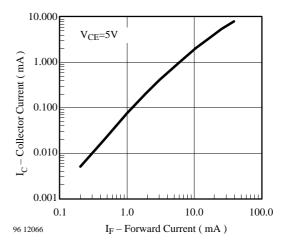


Figure 7. Collector Current vs. Forward Current

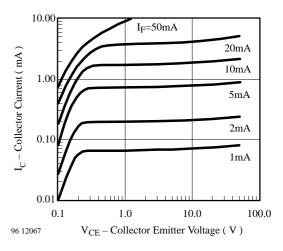


Figure 8. Collector Current vs. Collector Emitter Voltage

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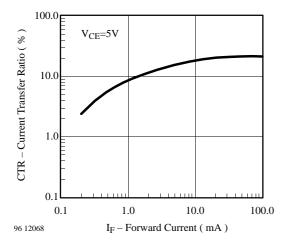


Figure 9. Current Transfer Ratio vs. Forward Current

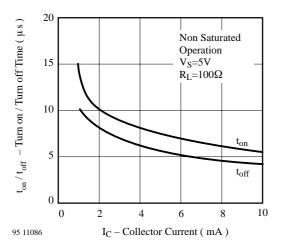


Figure 10. Turn on / off Time vs. Collector Current

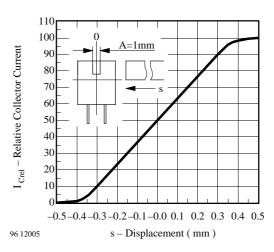


Figure 11. Relative Collector Current vs. Displacement

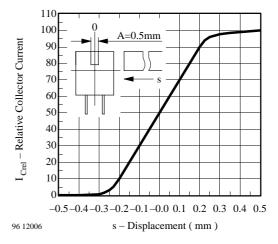


Figure 12. Relative Collector Current vs. Displacement

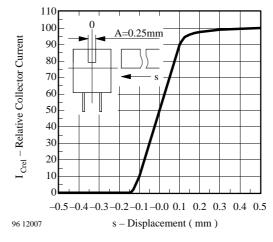
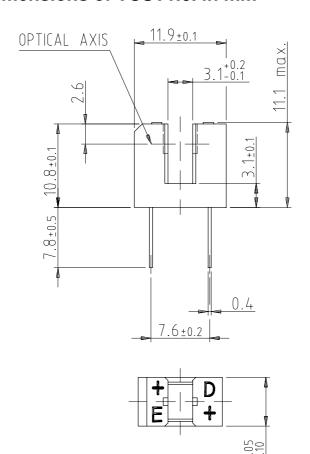


Figure 13. Relative Collector Current vs. Displacement

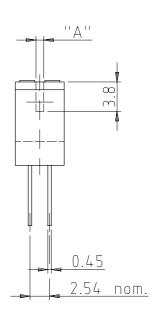


## Vishay Semiconductors

#### Dimensions of TCST1.0. in mm



weight: ca. 0.80g





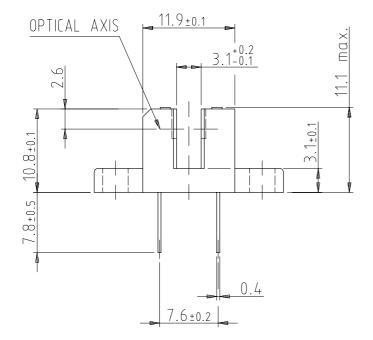
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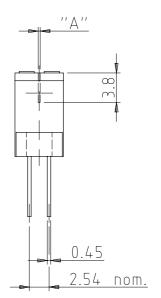
technical drawings according to DIN specifications

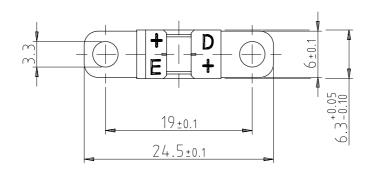
## Vishay Semiconductors

# VISHAY

## Dimensions of TCST2.0. in mm









weight: ca. 0.90g

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#### Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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